HLMP-EGxx, HLMP-ELxx and HLMP-EHxx

T-1¾ (5mm) Extra High Brightness AlInGaP LED Lamps

AVAGO TECHNOLOGIES

Data Sheet

Description

These Precision Optical Performance AlInGaP LEDs provide superior light output for excellent readability in sunlight and are extremely reliable. AlInGaP LED technology provides extremely stable light output over long periods of time. Precision Optical Performance lamps utilize the aluminum indium gallium phosphide (AlInGaP) technology.

These LED lamps are untinted, T-1¾ packages incorporating second generation optics producing well defined spatial radiation patterns at specific viewing cone angles.

These lamps are made with an advanced optical grade epoxy offering superior high temperature and high moisture resistance performance in outdoor signal and sign application. The maximum LED junction temperature limit of +130°C enables high temperature operation in bright sunlight conditions. The epoxy contains both uv-a and uv-b inhibitors to reduce the effects of long term exposure to direct sunlight.

Benefits

- Superior performance for outdoor environments
- Suitable for auto-insertion onto PC board

Features

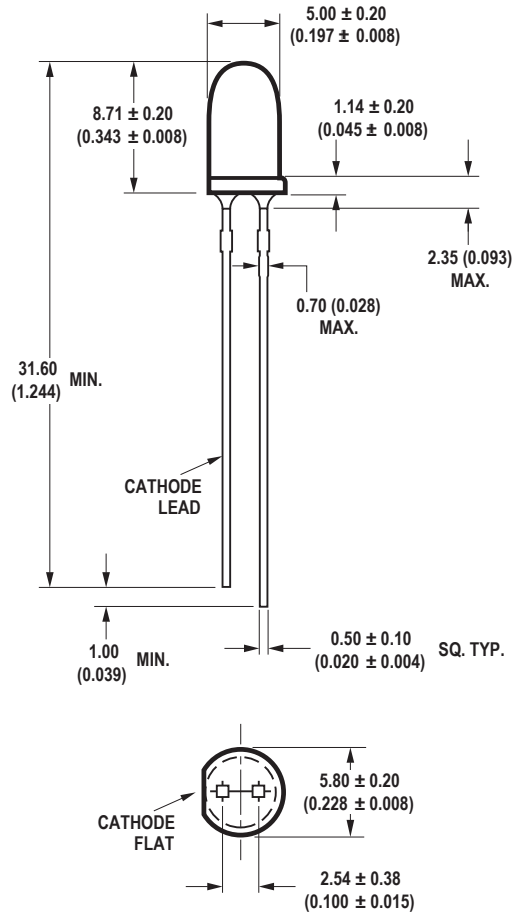
- Viewing angle: 15°, 23°, 30°
- High luminous output
- Colors:
  - 590nm Amber
  - 615nm Red-Orange
  - 626nm Red
- Package options:
  - With or without lead standoff
- Superior resistance to moisture

Applications

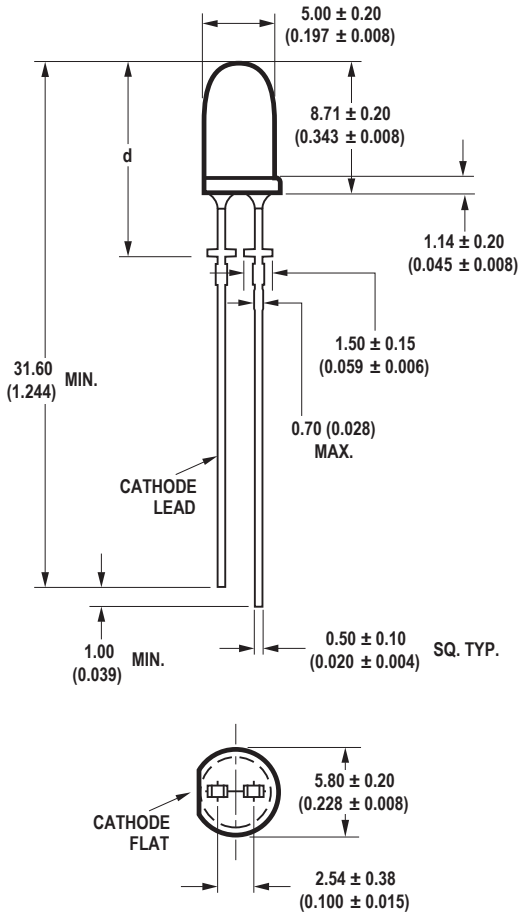
- Traffic management:
  - Traffic signals
  - Pedestrian signals
  - Work zone warning lights
  - Variable message signs
- Commercial outdoor advertising
  - Signs
  - Marquees

Package Dimension

A

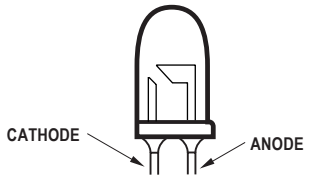


B



NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS (INCHES).
2. LEADS ARE MILD STEEL, SOLDER DIPPED.
3. TAPERS SHOWN AT TOP OF LEADS (BOTTOM OF LAMP PACKAGE) INDICATE AN EPOXY MENISCUS THAT MAY EXTEND ABOUT 1 mm (0.040 in.) DOWN THE LEADS.
4. RECOMMENDED PC BOARD HOLE DIAMETERS:
   - LAMP PACKAGE A WITHOUT STAND-OFFS: FLUSH MOUNTING AT BASE OF LAMP PACKAGE = 1.143/1.067 (0.044/0.042).
   - LAMP PACKAGE B WITH STAND-OFFS: MOUNTING AT LEAD STAND-OFFS = 0.965/0.889 (0.038/0.035).
5. FOR DOME HEIGHTS ABOVE LEAD STAND-OFF SEATING PLANE, d, LAMP PACKAGE B, SEE TABLE.
6. FOR IDENTIFICATION OF POLARITY AFTER THE LEADS ARE TRIMMED OFF, PLEASE REFER TO THE ILLUSTRATION BELOW:



7. MAJOR HEAT PATH IS THROUGH THE ANODE LEAD

PART NO.	d
HLMP-XX13	12.42 ± 0.25 (0.489 ± 0.010)
HLMP-XX23	11.59 ± 0.25 (0.446 ± 0.010)
HLMP-XX37	11.96 ± 0.25 (0.471 ± 0.010)

Device Selection Guide

Typical Viewing Angle 2θ½ (Deg) [4]	Color and Dominant Wavelength (nm), Typ. [3]	Lamps without Standoffs on Leads (Outline Drawing A)	Lamps with Standoffs on Leads (Outline Drawing B)	Luminous Intensity Iv (mcd) [1,2,5] @ 20mA	
				Min.	Max.
15°	Amber 590	HLMP-EL12-VY0DD	HLMP-EL13-VY0DD	4200	12000
		HLMP-EL12-XYKDD		7200	12000
	Red-Orange 615	HLMP-EH12-VY0DD	HLMP-EH13-VY0DD	4200	12000
	Red 626	HLMP-EG12-VY0DD	HLMP-EG13-VY0DD	4200	12000
		HLMP-EG12-WX0DD		5500	9300
23°	Amber 590	HLMP-EL22-UXKDD	HLMP-EL23-UXKDD	3200	9300
		HLMP-EL22-UX0DD	HLMP-EL23-UX0DD	3200	9300
		HLMP-EL22-VWKDD		4200	7200
	Red-Orange 615	HLMP-EH22-TW0DD	HLMP-EH23-TW0DD	2500	7200
	Red 626	HLMP-EG22-UX0DD	HLMP-EG23-UX0DD	3200	9300
		HLMP-EG22-VW0DD		4200	7200
30°	Amber 590	HLMP-EL35-TW0DD	HLMP-EL37-TW0DD	2500	7200
		HLMP-EL35-TWKDD	HLMP-EL37-TWKDD	2500	7200
		HLMP-EL35-UVKDD		3200	5500
	Red-Orange 615	HLMP-EH35-SV0DD	HLMP-EH37-SV0DD	1900	5500
	Red 626	HLMP-EG35-TW0DD	HLMP-EG37-TW0DD	2500	7200
		HLMP-EG35-UV0DD		3200	5500

Notes:
1. The luminous intensity is measured on the mechanical axis of the lamp package.
2. The optical axis is closely aligned with the package mechanical axis.
3. Dominant wavelength, λd, is derived from the CIE Chromaticity Diagram and represents the color of the lamp.
4. θ½ is the off-axis angle where the luminous intensity is half the on-axis intensity.
5. Tolerance for each intensity bin limit is ± 15%.

Part Numbering System

HLMP – E x x x - x x x x x

Mechanical Options
00 : Bulk Packaging
DD : Ammo Pack
YY : Flexi-Bin; Bulk Packaging
ZZ : Flexi-Bin; Ammo Pack

Color Bin Selections
0 : Full color distribution
2 : Amber color bin 2 only
4 : Amber color bin 4 only
K : Amber color bin 2 and 4 only
Z : Special Vf Bin Range

Maximum Intensity Bin
0 : No maximum intensity bin limitation

Minimum Intensity Bin

Viewing Angle and Lead Standoffs
12 : 15 deg without lead standoffs
13 : 15 deg with lead standoffs
22 : 23 deg without lead standoffs
23 : 23 deg with lead standoffs
35 : 30 deg without lead standoffs
37 : 30 deg with lead standoffs

Color
G : 626nm Red
H : 615nm Red-Orange
L : 590nm Amber

Absolute Maximum Ratings at $T_A = 25°C$

DC Forward Current [1]	50 mA
Peak Pulsed Forward Current	100 mA
Average Forward Current	30 mA
Reverse Voltage (Ir = 100 µA)	5 V
Operating Temperature	−40°C to +100°C
Storage Temperature	−40°C to +120°C
Wave Soldering Temperature[2]	250°C for 3 seconds
Solder Dipping Temperature[2]	260°C for 5 seconds

Notes:
1. Derate linearly as shown in Figure 4.
2. 1.59mm (0.060 in.) below body

Electrical/ Optical Characteristics at $T_A = 25^oC$

Parameter	Symbol	Minimum	Average	Maximum	Units	Test Condition
Forward Voltage						$I_F = 20mA$
Amber			2.20			
Red	V_F	1.80	2.10	2.40	V	
Red-Orange			2.00			
Peak Wavelength						$I_F = 20mA$
Amber			590			
Red	λ_{PEAK}		626		nm	
Red-Orange			615			
Dominant Wavelength [1]						$I_F = 20mA$
Amber		584.5		594.5		
Red	λ_d	620.0		630.0	nm	
Red-Orange		612.0		621.7		
Reverse Voltage	V_R	5			V	$I_R = 100\mu A$
Spectral Halfwidth	$\Delta\lambda_{½}$		17		nm	$I_F = 20$ mA
Capacitance	C		40		pF	$V_F = 0$, f = 1 MHz
Thermal Resistance	$R\theta_{J-PIN}$		240		$^oC/W$	LED Junction-to-Anode Lead
Luminous Efficacy [2]						Emitted Luminous Flux/Emitted Radiant
Amber			480			Flux
Red	η_V		150		lm/W	
Red-Orange			260			
Luminous Flux			1300		mlm	$I_F = 20mA$
Luminous Efficiency			30		lm/W	Emitted Luminous Flux/ Electrical Power

Notes:
1. The dominant wavelength, λd is derived from the CIE Chromaticity Diagram referenced to Illuminant E. Tolerance for each color of dominant wavelength is +/- 0.5nm.
2. The radiant intensity, Ie in watts per steradian, maybe found from the equation Ie = Iv / ηV where Iv is the luminous intensity in candela and ηV is the luminous efficacy in lumens/watt.

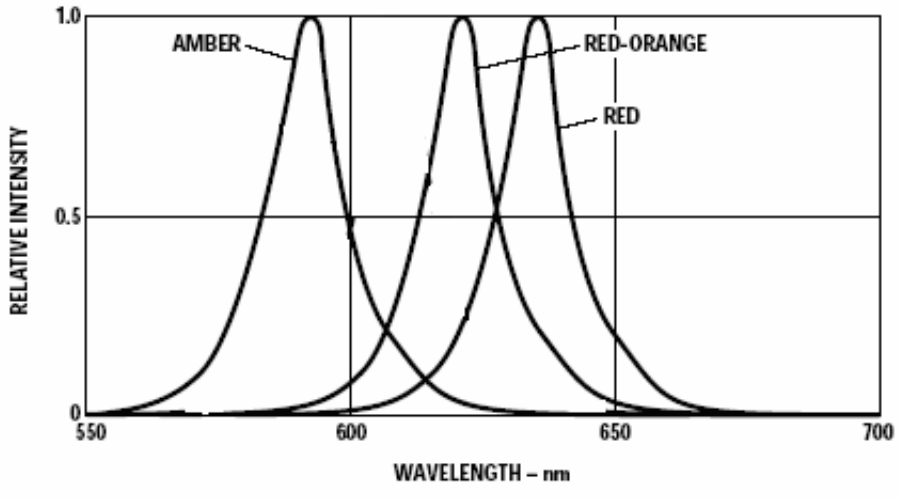


Figure 1. Relative intensity vs. peak wavelength

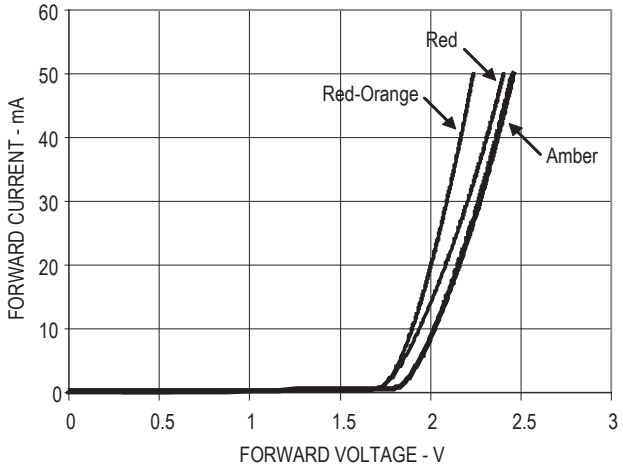


Figure 2. Forward current vs. forward voltage

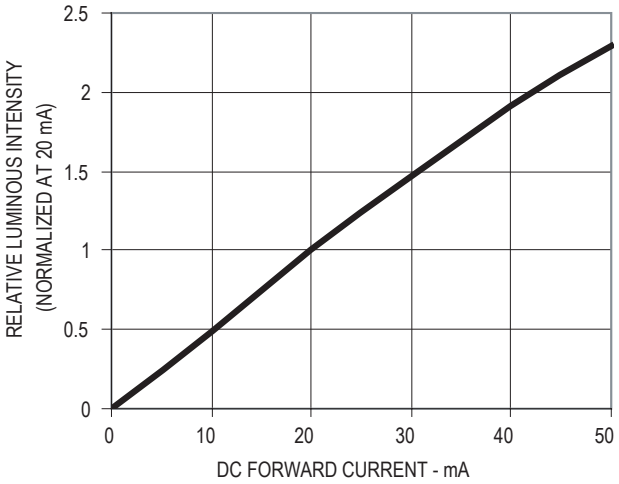


Figure 3. Relative luminous intensity vs. forward current

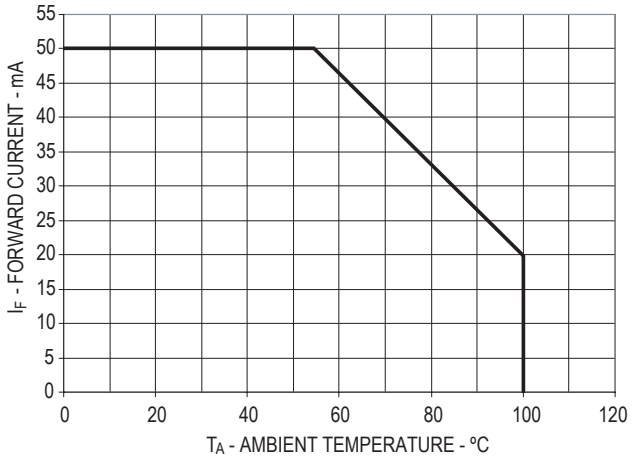


Figure 4. Maximum forward current vs. ambient temperature

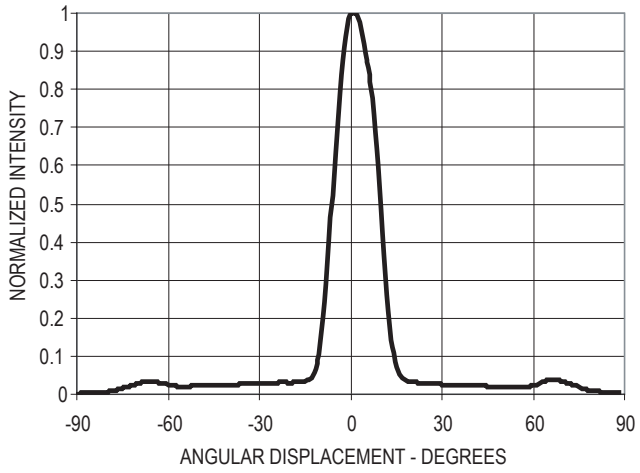


Figure 5. Representative spatial radiation pattern for 15° viewing angle lamps

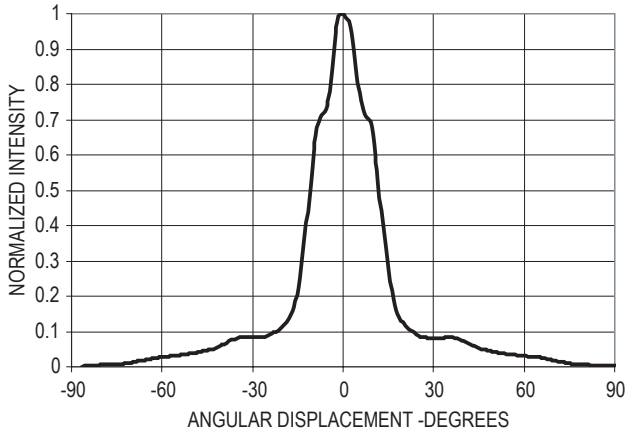


Figure 6. Representative spatial radiation pattern for 23° viewing angle lamps

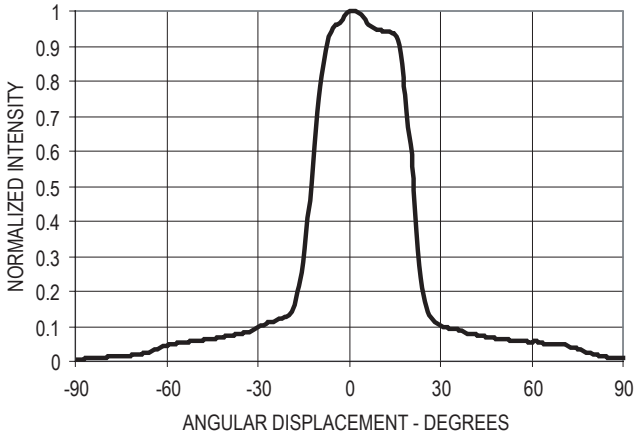


Figure 7. Representative spatial radiation pattern for 30° viewing angle lamps

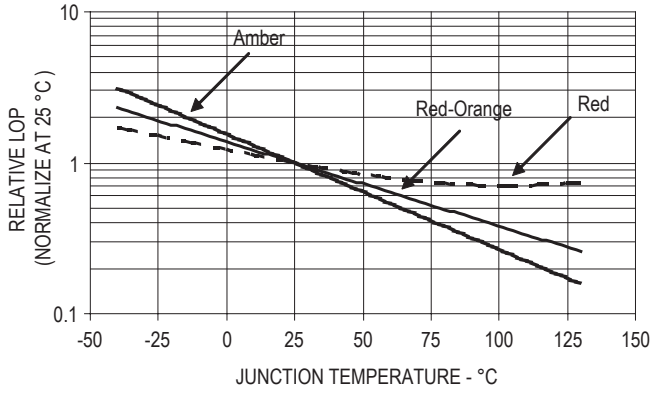


Figure 8. Relative light output vs. junction temperature

Intensity Bin Limits (mcd at 20mA)

Bin Name	Minimum	Maximum
R	1500	1900
S	1900	2500
T	2500	3200
U	3200	4200
V	4200	5500
W	5500	7200
X	7200	9300
Y	9300	12000
Z	12000	16000
1	16000	21000
2	21000	27000

Tolerance for each bin limit is ± 15%

Forward Voltage Bin Limits (V at 20mA)

Bin Name	Minimum	Maximum
VD	1.8	2.0
VA	2.0	2.2
VB	2.2	2.4

Tolerance for each bin limit is ± 0.05V

Amber Color Bin Limits (nm at 20mA)

Bin Name	Minimum	Maximum
1	584.5	587.0
2	587.0	589.5
4	589.5	592.0
6	592.0	594.5

Tolerance for each bin limit is ± 0.5nm
Note: Bin categories are established for classification of products. Products may not available in all bin categories.

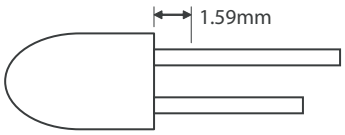
Precautions:

Lead Forming:

- The leads of an LED lamp may be performed or cut to length prior to insertion and soldering on PC board.
- If lead forming is required before soldering, care must be taken to avoid any excessive mechanical stress that induced into the LED package. Otherwise, cut the leads to applicable length after soldering process at room temperature. The solder joint formed will absorb the mechanical stress, due to the lead cutting, from traveling to the LED chip die attach and wirebond.
- For better control, it is recommended to use proper tool to precisely form and cut the leads to applicable length rather than doing it manually.

Soldering condition:

- Care must be taken during PCB assembly and soldering process to prevent damage to the LED component.
- The closest manual soldering distance of the soldering heat source (soldering iron's tip) to the body is 1.59mm. Soldering the LED closer than 1.59mm might damage the LED.



- Recommended soldering condition:

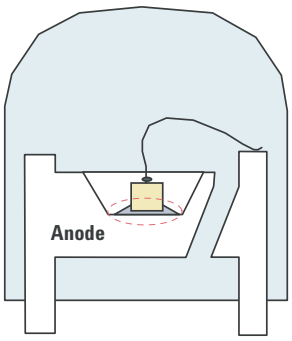
	Wave Soldering	Manual Solder Dipping
Pre-heat temperature	105 °C Max.	-
Preheat time	30 sec Max	-
Peak temperature	250 °C Max.	260 °C Max.
Dwell time	3 sec Max.	5 sec Max

- Wave soldering parameter must be set and maintain according to the recommended temperature and dwell time. Customer is advised to daily check on the soldering profile to ensure that the soldering profile is always conforming to recommended soldering condition.

Note:

1. PCB with different size and design (component density) will have different heat mass (heat capacity). This might cause a change in temperature experienced by the board if same wave soldering setting is used. So, it is recommended to re-calibrate the soldering profile again before loading a new type of PCB.
2. Avago Technologies' high brightness LED are using high efficiency LED die with single wire bond as shown below. Customer is advised to take extra precaution during wave soldering to ensure that the maximum wave temperature is not exceeding 250°C. Over-stressing the LED during soldering process might cause premature failure to the LED due to delamination.

Avago Technologies LED configuration



AlInGaP Device

Note: Electrical connection between bottom surface of LED die and the lead frame material through conductive paste of solder.

- If necessary, use fixture to hold the LED component in proper orientation with respect to the PCB during soldering process.
- At elevated temperature, the LED is more susceptible to mechanical stress. Therefore, PCB must allowed to cool down to room temperature prior to handling, which includes removal of jigs, fixtures or pallet.
- Special attention must be given to board fabrication, solder masking, surface platting and lead holes size and component orientation to assure the solderability.
- Recommended PC board plated through holes size for LED component leads.

LED component lead size	Diagonal	Plated through hole diameter
0.457 x 0.457 mm (0.018 x 0.018 inch)	0.646 mm (0.025 inch)	0.976 to 1.078 mm (0.038 to 0.042 inch)
0.508 x 0.508 mm (0.020 x 0.020 inch)	0.718 mm (0.028 inch)	1.049 to 1.150 mm (0.041 to 0.045 inch)

- Under sizing of plated through hole can lead to twisting or improper LED placement during auto insertion. Over sizing plated through hole can lead to mechanical stress on the epoxy lens during clinching.

Note: Refer to application note AN1027 for more information on soldering LED components.

Recommended Wave Soldering Profile

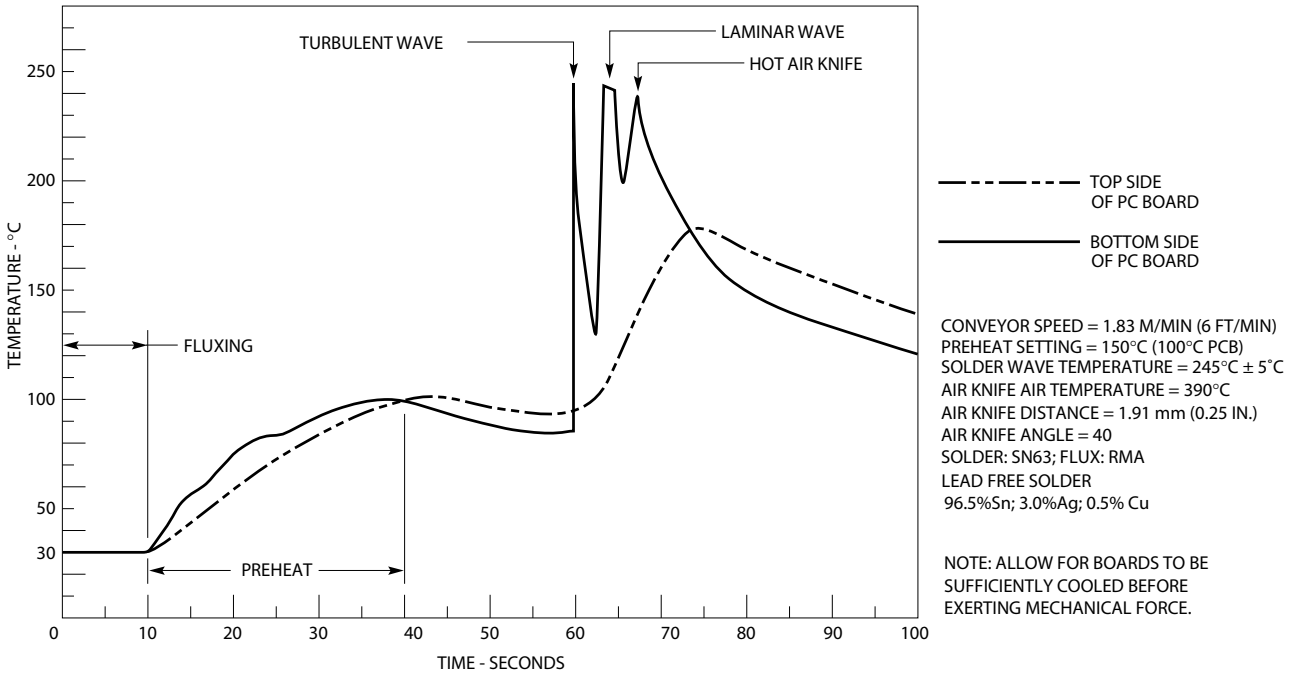
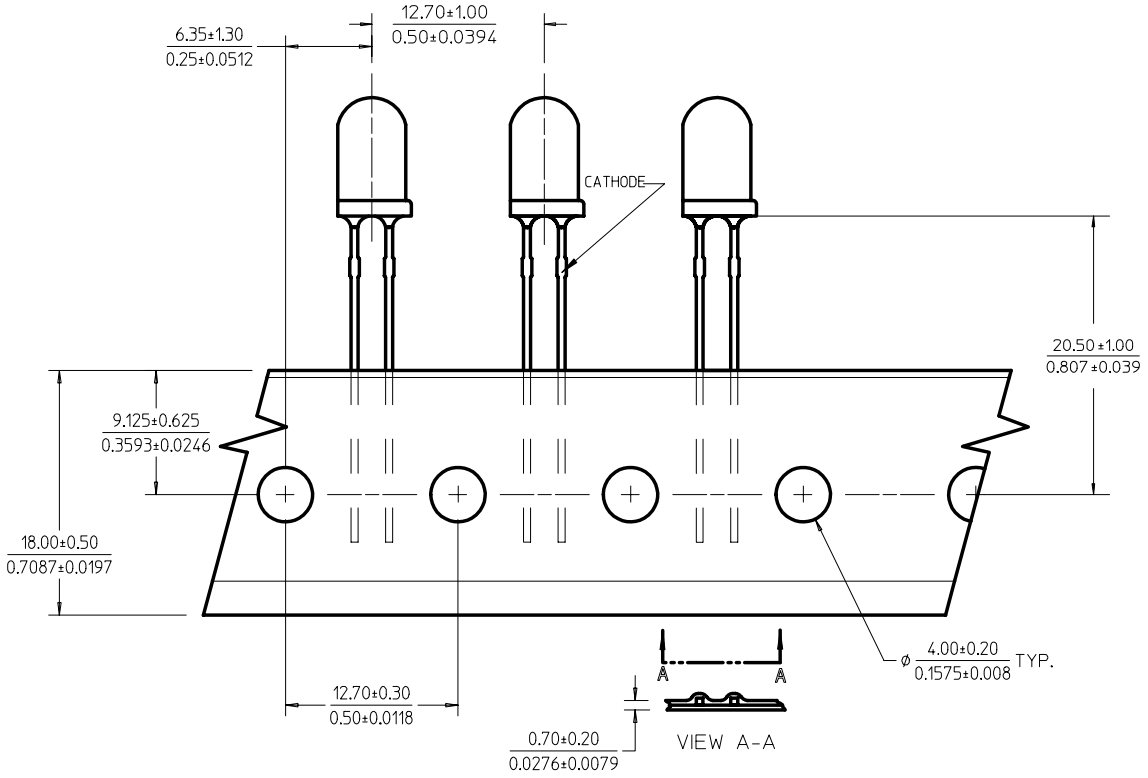


Figure 9. Recommended Wave Soldering Profile

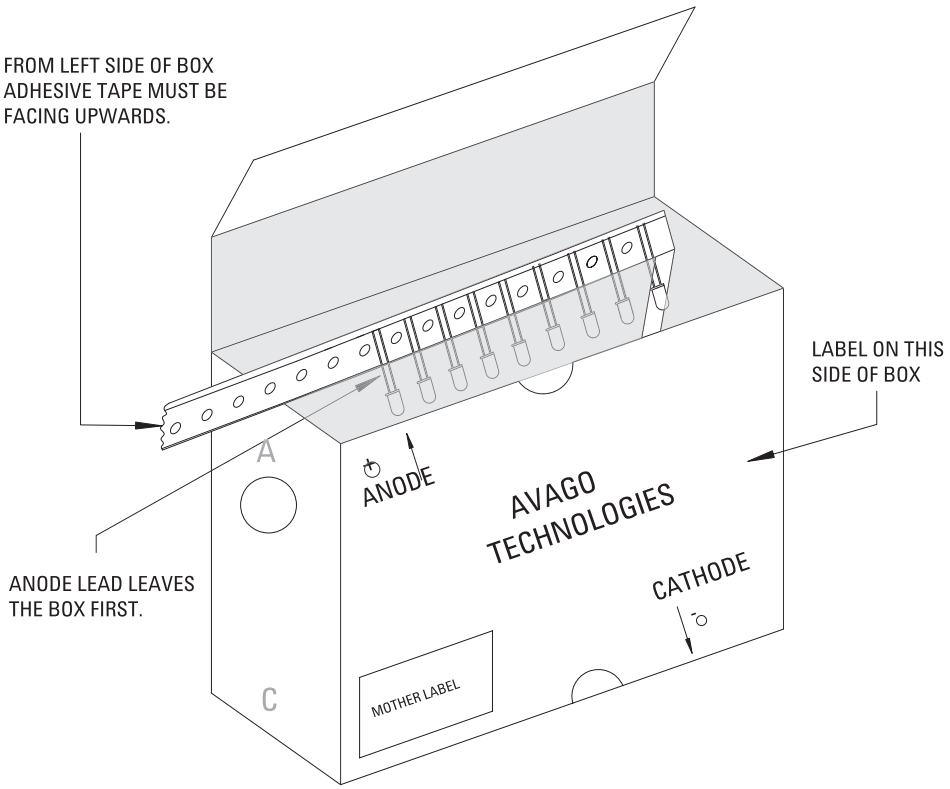
Ammo Packs Drawing



Note: The ammo-packs drawing is applicable for packaging option –DD & -ZZ and regardless standoff or non-standoff

Figure 10. Dimension for ammo pack

Packaging Box for Ammo Packs



Note: The dimension for ammo pack is applicable for the device with standoff and without standoff.

Figure 11. The arrangement of unit in ammo pack

For product information and a complete list of distributors, please go to our web site: **www.avagotech.com**

AV02-0086EN - April 12, 2007